

Discription

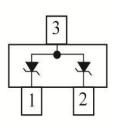
The MMBZ6V8ALT1G protects sensitive semiconductor components from damage or upset due to electrostatic discharge (ESD) and other voltage induced transient events. Excellent clamping capability, low leakage, low capacitance, and fast response time provide best in class protection on designs that are exposed to ESD. It gives designer the flexibility to protect 2 unidirectional line in applications where arrays are not practical.



SOT-23

Features

- ♦SOT-23 package allows either two separate unidirectional configurations or a single bidirectional configuration.
- ♦ Working peak reverse voltage 4.5V
- ♦ Standard Zener breakdown voltage 6.8V
- ♦ Peak power 24 or Watts @ 1.0ms (unidirectional) per Figure 6 Waveform
- ♦ESD Rating: Class 3B (>16kV) per the Human Body Model Class C (>400V) per Machine Model
- $\diamond \text{ESD}$ Rating of IEC61000-4-2 level 4, $\pm\,30\text{kV}$ contact Discharge
- ♦Low leakage < 5.0µA</p>



Circuit Diagram

Ordering information

Product ID	Pack	Qty(PCS)
MMBZ6V8ALT1G	SOT-23	3000

Absolute Ratings (T_{amb}=25°C)

Symbol	Parameter	Value	Units
P _{PP}	Peak Pulse Power (t _p = 8/20μs)	24	W
TL	Maximum lead temperature for soldering during 10s	260	°C
T _{stg}	Storage Temperature Range	-55 to +150	°C
T _{op}	Operating Temperature Range	-40 to +125	°C
T _j	Maximum junction temperature	150	°C
	IEC61000-4-2 (ESD) air discharg		KV
	contact discharge	±30	IXV

ELECTRICAL CHARACTERISTICS (Tamb=25°C)

		V_{RWM}	I_R	V_{BR}				Z_{ZT}	Z_{ZK}		V _C	
Part Number	Device Marking	(V)	(μΑ)		(V)		(mA)	(Ω)	(Ω)	(mA)	(V)	(A)
			@ V _{RWM}	Min	Nom	Max	@ I _⊤	Max @I _{ZT}	Max	@ I _{zK}	Max	@ I _{PP}
MMBZ6V8ALT1G	6A8	4.5	0.5	6.46	6.8	7.14	1.0				9.6	2.5

 V_F =0.9V Max @ I_F =10mA

Note 1: Surge Current waveform per Figure 5



ELECTRICAL CHARACTERISTICS CURVE

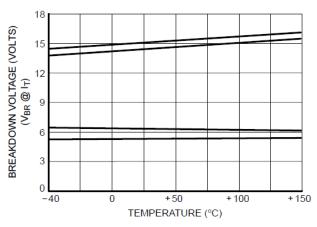


Figure 1. Typical Breakdown Voltage versus Temperature

(Upper curve for each voltage is bidirectional mode, lower curve is unidirectional mode)

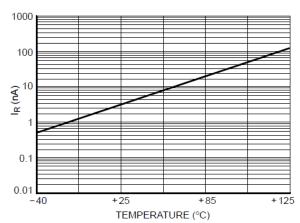


Figure 2. Typical Leakage Current versus Temperature

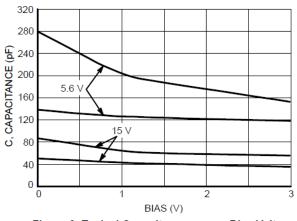


Figure 3. Typical Capacitance versus Bias Voltage (Upper curve for each voltage is unidirectional mode, lower curve is bidirectional mode)

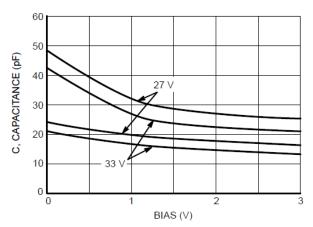


Figure 4. Typical Capacitance versus Bias Voltage
(Upper curve for each voltage is unidirectional mode,
lower curve is bidirectional mode)

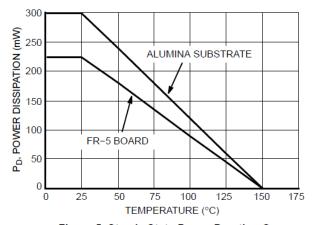


Figure 5. Steady State Power Derating Curve



ELECTRICAL CHARACTERISTICS CURVE

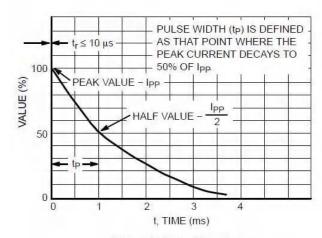


Figure 6. Pulse Waveform

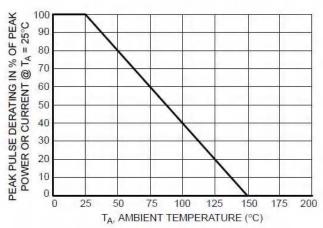


Figure 7. Pulse Derating Curve

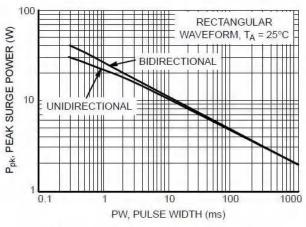


Figure 8. Maximum Non-repetitive Surge Power, P_{pk} versus PW

Power is defined as $\bigvee_{RSM} x \mid_{Z}(pk)$ where \bigvee_{RSM} is the clamping voltage at $\mid_{Z}(pk)$.

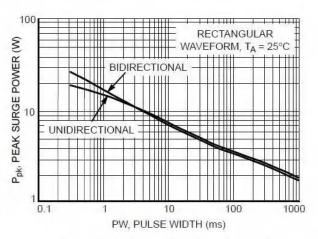
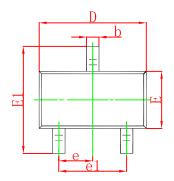


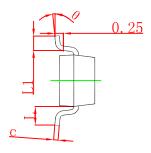
Figure 9. Maximum Non-repetitive Surge Power, P_{pk}(NOM) versus PW

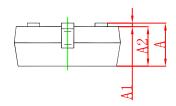
Power is defined as $V_Z(NOM) \times I_Z(pk)$ where $V_Z(NOM)$ is the nominal Zener voltage measured at the low test current used for voltage classification.



SOT-23 Package Outline Dimensions

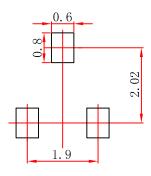






Symbol	Dimensions	In Millimeters	Dimensions In Inches			
	Min	Max	Min	Max		
Α	0.900	1.150	0.035	0.045		
A1	0.000	0.100	0.000	0.004		
A2	0.900	1.050	0.035	0.041		
b	0.300	0.500	0.012	0.020		
С	0.080	0.150	0.003	0.006		
D	2.800	3.000	0.110	0.118		
E	1.200	1.400	0.047	0.055		
E1	2.250	2.550	0.089	0.100		
е	0.950	TYP	0.037 TYP			
e1	1.800	2.000	0.071	0.079		
L	0.550	REF	0.022 REF			
L1	0.300	0.500	0.012	0.020		
θ	0°	8°	0°	8°		

SOT-23 Suggested Pad Layout



Note:

- 1.Controlling dimension:in millimeters.
- 2.General tolerance:± 0.05mm.
 3.The pad layout is for reference purposes only.

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